Universal AC/DC

Photoelectric Sensors

BEN Series



Features

- · Small and power supply built-in type
- Easy installation with indicators on product
- · Light ON / Dark ON mode selectable by switch
- Status and output indication
- \cdot Built-in IC photo diode for disturbing light and electrical noise

Specifications

Model	BEN10M-T	ВЕN5М-М □	ВЕΝЗМ-Р □	BEN300-D
Sensing type	Through-beam	Retroreflective	Polarized retroreflective	Diffuse reflective
Sensing distance	10 m	0.1 to 5 m ⁰¹⁾	0.1 to 3 m ⁰¹⁾	300 mm ⁰²⁾
Sensing target	Opaque materials	Opaque materials	Opaque materials	Opaque, translucent materials
Min. sensing target	≥ Ø 16 mm	≥ Ø 60 mm	≥ Ø 60 mm	-
Hysteresis	-	-	-	≤ 20 % of sensing distance
Response time	AC/DC power, relay contact output model: ≤ 20 ms DC power, solid state (transistor) output model: ≤ 1 ms			
Light source	Infrared	Infrared	Red	Infrared
Peak emission wavelength	850 nm	940 nm	660 nm	940 nm
Sensitivity adjustment	-	YES (Adjuster)	YES (Adjuster)	YES (Adjuster)
Operation mode	Light ON mode - Dark ON mode selectable (Adjuster)			
Indicator	Operation indicator (red), stability indicator (green), power indicator (red) 033			
Approval	C € EHL			
Unit weight (AC/DC power)	≈ 354 g	≈ 208 g	≈ 208 g	≈ 195 g
Unit weight (DC power)	≈ 342 g	≈ 200 g	≈ 200 g	≈ 187 g

- 01) Reflector (MS-2) 02) Non-glossy white paper 100 × 100 mm 03) Only for the emitter

Output method	AC/DC power, relay contact output	DC power, solid state (transistor) output	
Power supply	24-240 VAC ~ ± 10 % 50/60 Hz 24-240 VDC == ± 10 % (ripple P-P: ≤ 10 %)	12-24 VDC== ± 10 % (ripple P-P: ≤ 10 %)	
Power / current consumption	≤ 4 VA	It depends on the sensing type	
Through-beam	-	Emitter: ≤ 50 mA, receiver: ≤ 50 mA	
Reflective	-	≤ 50 mA	
Control output	Relay contact output	NPN open collector - PNP open collector simultaneous output	
Contact capacity	250 VAC \sim 3 A of resistance load, 30 VDC= 3 A of resistance load	-	
Contact composition	1c		
Relay life cycle	Mechanical: ≥ 50,000,000 Electrical: ≥ 100,000		
Load voltage	-	≤ 30 VDC	
Load current		≤ 200 mA	
Residual voltage		NPN: ≤ 1 VDC==, PNP: ≤ 2.5 VDC==	
Protection circuit	-	Reverse power protection circuit, output short overcurrent protection circuit	
Insulation resistance	≥ 20 MΩ (500 VDC megger)		
Insulation type	Double or strong insulation (dielectric voltage between the measured input and the power: 1 kV)	-	
Noise immunity	± 1,000 VDC== the square wave noise	±240 VDC== the square wave noise	





Dielectric strength	1,000 VAC ~ 50/60 Hz for 1 min		
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours		
Vibration (malfunction)	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 10 min		
Shock	500 m/s 2 (\approx 50 G) in each X, Y, Z direction for 3 times		
Shock (malfunction)	100 m/s² (\approx 10 G) in each X, Y, Z direction for 3 times -		
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx		
Ambient temperature	-20 to 65 °C, storage: -20 to 70 °C (no freezing or condensation)		
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)		
Protection rating	IP50 (IEC standard)		
Connection	Cable type		
Cable spec.	Ø 5 mm, Emitter: 2-wire, AC/DC power: 5-wire, DC power: 4-wire, 2 m		
Wire spec.	AWG22 (0.08 mm, 60-core), insulator outer diameter: Ø 1.25 mm		
Material	Case and case cover: heat resistant ABS, sensing part: PC (polarized retroreflective: PMMA)		